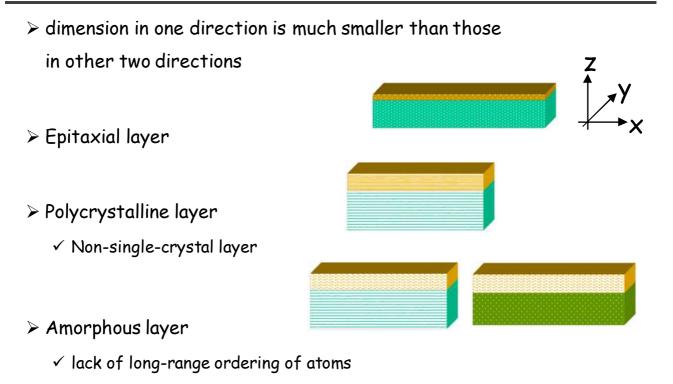
# X-ray for characterization of thin films

**CHAN PARK** 

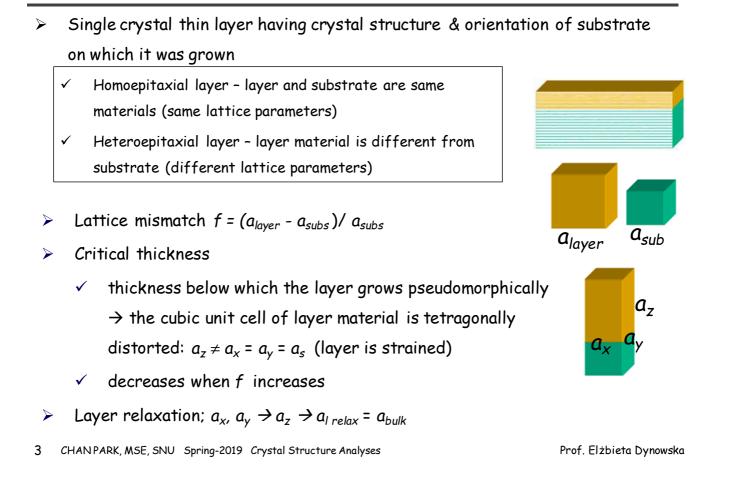
Many slides from the ppt made by Bruker, Panalytical, Rigaku and Dr. Scott A. Speakman (prism.mit.edu/xray) were used

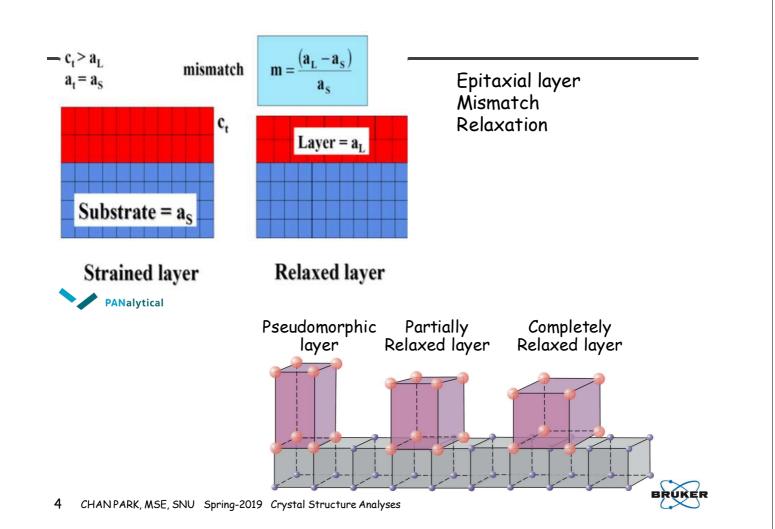
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#### Thin layer



# Epitaxial layer





- > crystalline state of layer/layers epi?; polycrystalline?; amorphous?
- > crystal quality chemical composition
- Thickness

surface and interface roughness

mismatch

misorientation

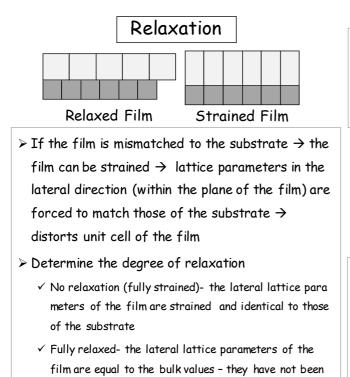
dislocation

- > superlattice period
- ➤ mismatch
- ➤ relaxation
- $\succ$  misorientation
- > dislocation density
- > mosaic spread
- > curvature
- > inhomogeneity

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# Relaxation (Lattice Strain)



Curvature

mosaic spread

curvature

relaxation

inhomogeneity



#### Dislocations

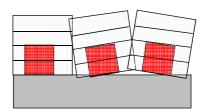
- Interface dislocations may form to relieve lattice strain between film and substrate with a large amount of mismatch.
- Slip dislocations are created by plastic deformation due to thermal or mechanical strain in the layer

distorted at all

### Mosaic Spread

Mosaicity is created by slight misorientations of different crystals as they nucleate and grow on the substrate. When the crystals join, they form low e nergy boundaries.

In the ideal case, each nuclei (red) is perfectly oriented. When the crystals grow and meet, there is perfect bonding between the crystallites  $\rightarrow$  no boundary



If the nuclei (red) are slightly misaligned  $\rightarrow$  low angle boundaries can be formed.

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#### Thin film structure types

Perfect Epitaxy	Single crystal film in perfect registry with a substrate. There are no defects in the film or the substrate.				
Nearly perfect Epitaxy	Single crystal film in nearly perfect registry with a substrate. Both film and substrate contain a low concentration of defects. Most defects are dislocations in the film.				
Textured epitaxial	ate All domain boundaries are very low anale/low energy boundaries				
Strongly textured polycrystalline	Film consists of grains with nearly perfect preferred orientation of all principle axes. This orientation is often strongly correlated to the substrate. Misorientation parameter for texture is small.				
Textured polycrystallineFilm consists of grains with a preferred orientation for 3 principle only along 1 axis out-of-plane.					
Polycrystalline	Film consists of randomly oriented grains.				
Amorphous	Film does not have long-range order.				

# Techniques $\leftrightarrow$ type of information of film

	Thick ness	Composition	Lattice Strai n/ Relaxation	Defects	Orien tation	Residual Stress	Crystalli te Size
Perfect Epitaxy	XRR HRXRD	HRXRD RC	Assume 100 %	Assume no ne	HRXRD		
Nearly perfect Epitaxy	XRR HRXRD	HRXRD RC	HRXRD	RC	HRXRD		
Textured epitaxial	XRR HRXRD	HRXRD	HRXRD IP-GIXD	RC	HRXRD		
Strongly textured Polyxtalline	XRR	XRPD IP-GIXD	IP-GIXD	XRPD, IP- GIXD	IP-GIX D PF	IP-GIXD	XRPD,I P-GIXD
Textured Polyxtalline	XRR	XRPD,GIXD or IP-GIXD		XRPD, GI XD OR IP- GIXD	PF	Psi	XRPD GIXD
Polyxtalline	XRR	XRPD, GIXD		XRPD GIXD	PF	Psi	XRPD GIXD
Amorphous	XRR						

HR- High Resolution XRD using coupled scan or RSM IP-GIXD- in-plane grazing incidence XRD RC- Rocking Curve PF- pole figure

XRR- X-Ray Reflectivity XRPD- X-ray powder diffraction

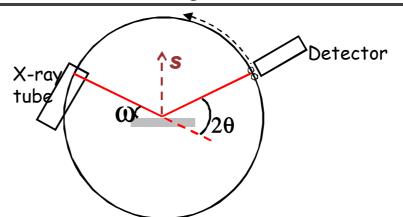
Psi- sin<sup>2</sup>psi using parallel beam

GIXD-grazing incidence XRD

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X-ray intensity as a function of omega and/or 2theta



> The incident angle w (omega) (X-ray source - sample)

> The diffraction angle  $2\theta$  (incident beam - detector)

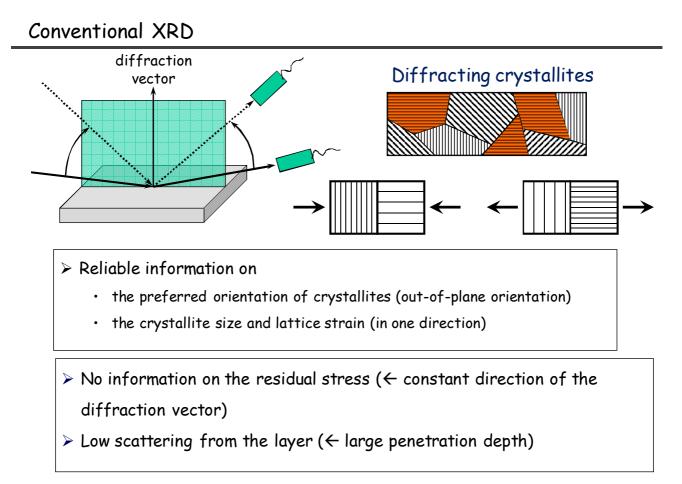
> Rocking Curve; X-ray intensity vs. Omega

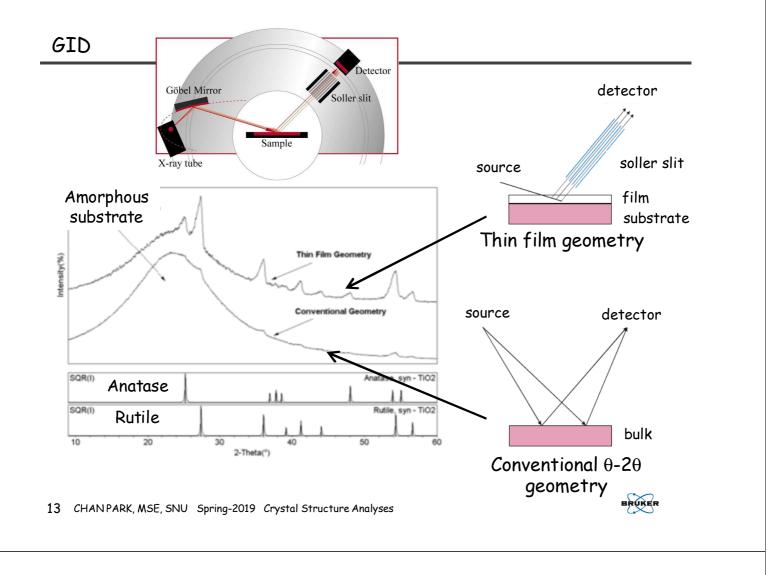
- > Detector Scan; X-ray intensity vs. 20 without changing Omega
- > Coupled Scan; X-ray intensity vs  $2\theta$ , but Omega also changes so that

$$\omega = \frac{1}{2} \times 2\theta + offset$$

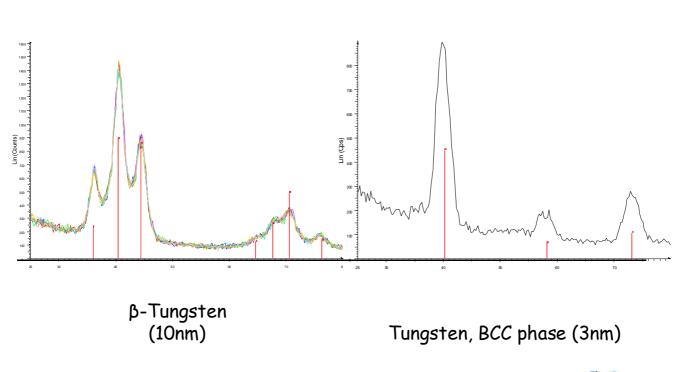
# X-ray technologies for thin films

- Grazing incident X-Ray diffraction (GID)
  - ✓ poly-crystalline thin films; phase ID, crystallite size, crystallinity
- > In-plane grazing incident diffraction (IP-GID)
  - ✓ Textured film and epitaxial film; in-plane orientation, in-plane lattice parameter, crystallinity, depth analysis
- ➢ <u>Rocking curves</u> → dislocation density, mosaic spread, curvature, misorientation, inhomogeneity, layer thickness, superlattice period, strain and composition profile, lattice mismatch, ternary composition, relaxation
- > <u>Coupled scans</u>  $\rightarrow$  lattice mismatch, ternary composition, relaxation, thickness, superlattice period
- ➤ <u>Reciprocal space map (RSM)</u> → composition, thickness (> 50 nm), mismatch, mosacity, defects profile, etc. (most complete amount of information that are needed for the analysis of strained films)
- ➤ <u>Reflectivity</u> → composition, thickness (5-150 nm), interface/surface roughness; works with non-epitaxial and even non-crystalline thin films
- > Grazing incident small-angle X-ray scattering (GISAXS)
  - ✓ pore structure (alignment), pore size distribution
- > <u>Pole figures</u>  $\rightarrow$  preferred orientation
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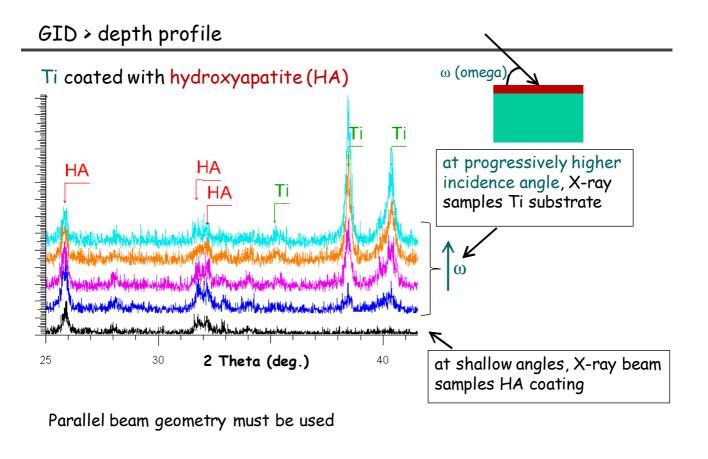




# GID > phase analysis on tungsten films

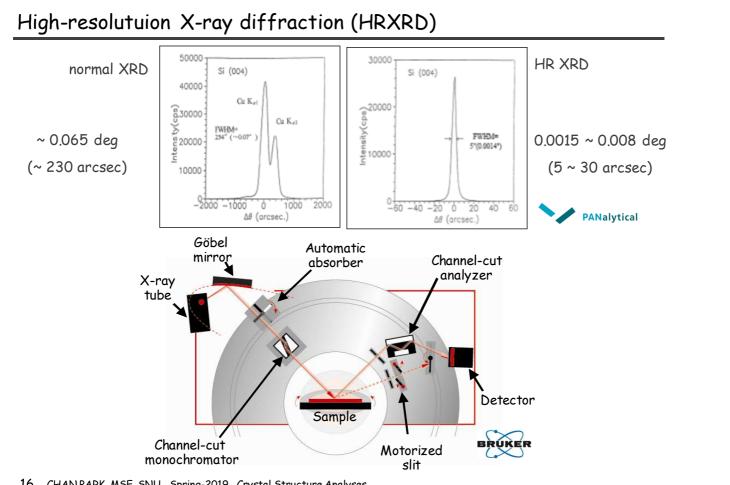




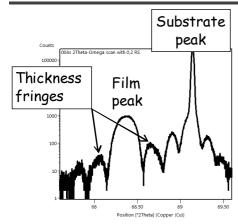


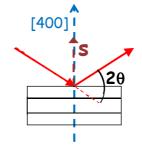
www.csec.ed.ac.uk/Instruments/D8\_diffractometer/D8\_GID.html 15 CHAN PARK, MSE, SNU Spring-2019 Crystal Structure Analyses

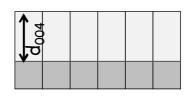




# Coupled diffraction scan $\rightarrow$ d-spacing and thickness







Coupled scan: ω & 2θ change in coupled manner so the direc tion being measured (scattering vector, s) does not change

> The peak position will give the d-spacing for the Bragg peak

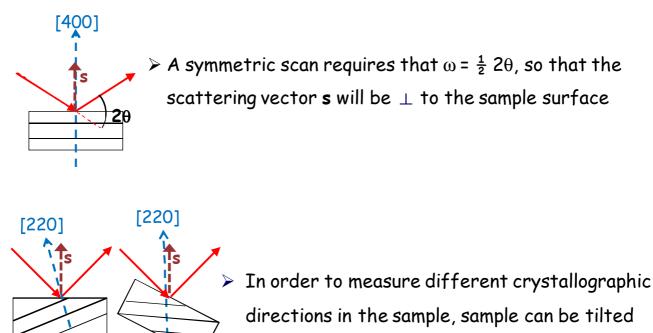
✓ This will provide information on anything that changes the lattice parameter of the unit cell, such as composition or strain/relaxation

✓ This will only provide measurement of the <u>lattice parameter in one direction</u>

- > The width of film's Bragg peak can be used to quantify film thickness
  - $\checkmark$  The thickness fringes can also be used to quantify the film thickness
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#### Sample tilt

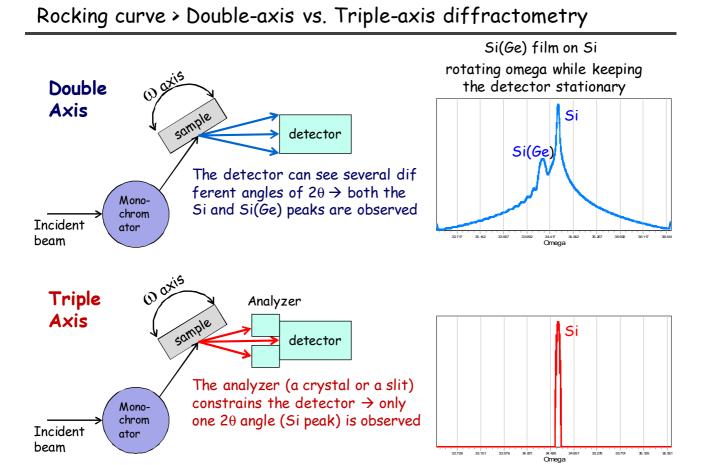


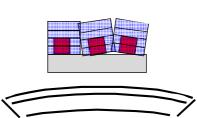
 $\rightarrow$  asymmetric scan

#### Rocking curve ( $\omega$ scan)

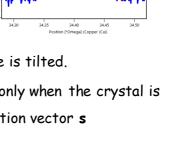
> The detector is set at a specific Bragg angle and the sample is tilted.

- > A perfect crystal will produce a very sharp peak, observed only when the crystal is properly tilted so that the plane normal is // to the diffraction vector s
- > Defects like mosaicity, dislocations, and curvature create d isruptions in the perfect periodicity of atomic planes
  - ✓ This is observed as broadening of the rocking curve
  - $\checkmark$  The center of the rocking curve is determined by the d-spacing o f the peaks
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[400] [400] ١Ě ω-δ ω+δ 2θ 2.0

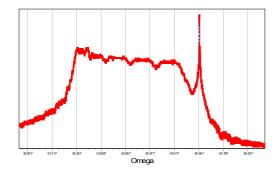


Two instrumental configurations for HRXRD

- > Double-axis (double-crystal)
  - $\checkmark$  The detector does not discriminate between different diffraction angles 20.
  - ✓ All Bragg angles are measured simultaneously (over a limited range)
  - ✓ The sample is rotated about its  $\omega$  axis (changing the incident angle) to produce a rocking curve (intensity vs  $\omega$ )
- Triple-axis (triple-crystal)
  - $\checkmark$  A slit or analyzer crystal determines the angular acceptance of the detector.
  - ✓ The analyser crystal enables to <u>distinguish between mosaic spread and strain contributions</u> <u>in the diffracted intensity distribution</u>.
  - ✓ While a rocking curve (intensity vs  $\omega$ ) can be measured, it is more common to collect data by using a coupled scan
  - ✓ As the sample is rotated about  $\omega$ , the detector is rotated at twice the rate so that  $2\theta = 2\omega$ , producing a coupled  $\omega$  2 $\theta$  scan
  - ✓ Reciprocal space maps are collected by collecting coupled scans at different ω offsets, where  $2\theta = 2ω - offset$
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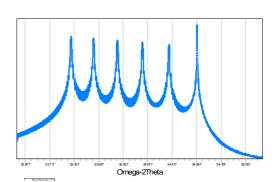
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# Double-axis rocking curve vs. Triple-axis coupled scan



The double-axis rocking curve
 a Si wafer coated with 5 slightly relaxed
 Si(Ge) layers of varying Ge concentration

- The Ge concentrations were 10, 20, 30,
  40, and 50%.
- > Each Ge layer was 500nm thick.



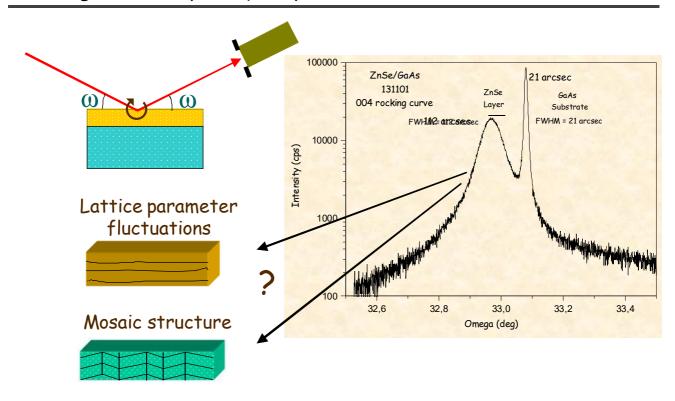
The triple-axis coupled omega-2theta scan of the same Si wafer

> A rocking curve in triple-axis mode can be collected for each individual peak to determine the tilt variation of each individual Si(Ge) layer

#### Triple-axis > coupled scans vs Reciprocal Space Map

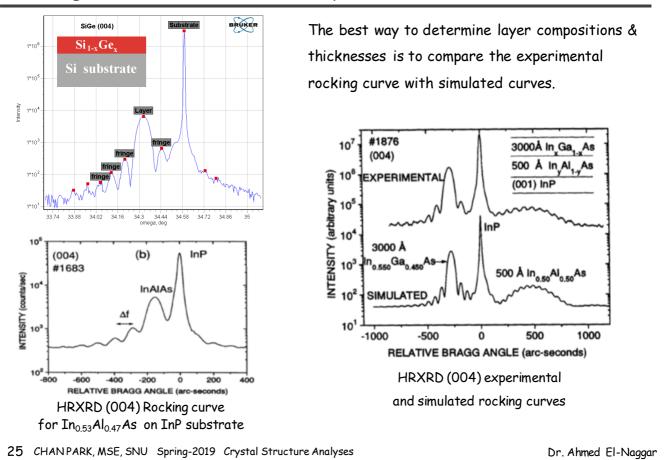
- > Coupled scan collects data as  $\omega$ -2 $\theta$ 
  - $\checkmark\,$  20 is moved at twice the rate as the sample rotation about  $\omega$
  - ✓  $2\theta = 2\omega + \text{tilt}$
  - ✓ This will observe peaks with different Bragg angles, but only for one specific tilt
  - ✓ If the epilayers are tilted w.r.t. the substrate, then a single coupled scan cannot observe both substrate and film peaks → must collect coupled scans for a range of tilts: this is the Reciprocal Space Map (RSM)
- > The **RSM** collects several  $\omega$ -2 $\theta$  coupled scans, but each coupled scan is collected with a slightly different tilt (offset) in the  $\omega$  direction
  - $\checkmark$  When the scan is collected, 20 still moves at twice the rate as the sample rotation so that 20 = 2 $\omega$  + tilt
  - ✓ The tilt value is slightly different for each coupled scan that is collected
  - ✓ Complete map of  $\omega$ -2 $\theta$  vs tilt ( $\omega$ )
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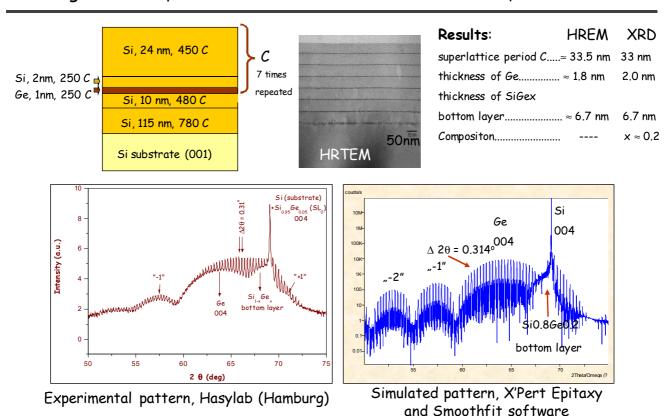


#### Rocking curve > crystal quality

#### Rocking curve > thickness and composition

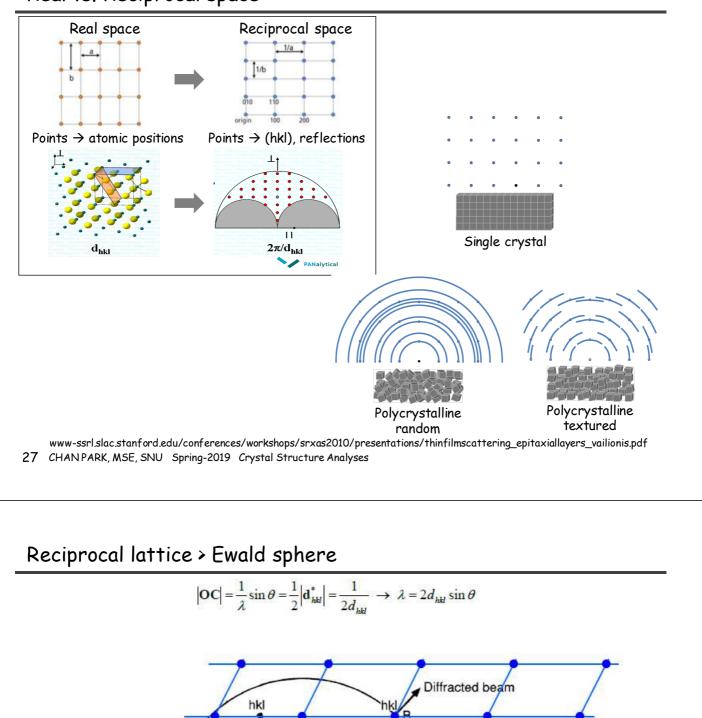


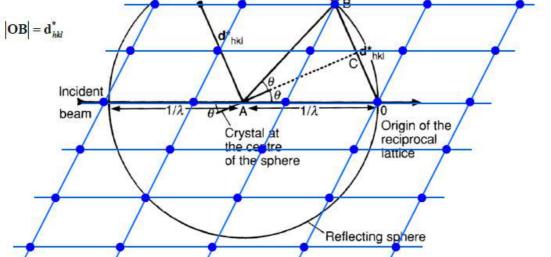
#### Rocking curve - superlattice of self-assembled ultra-small Ge quantum dots



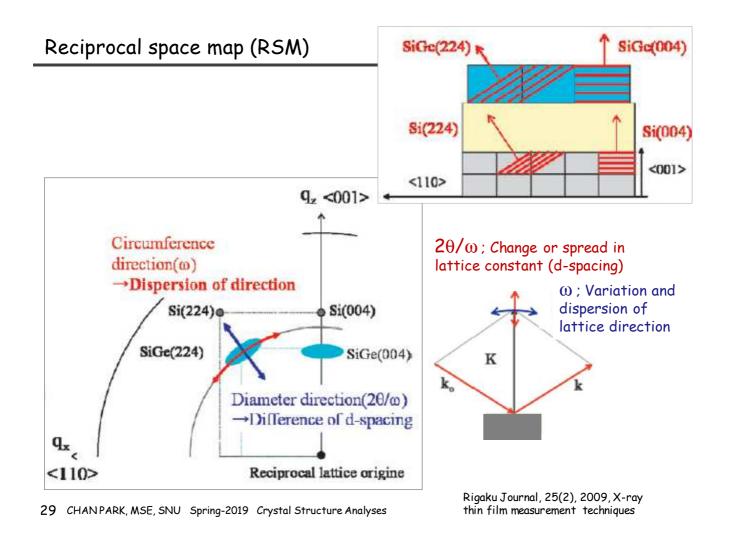
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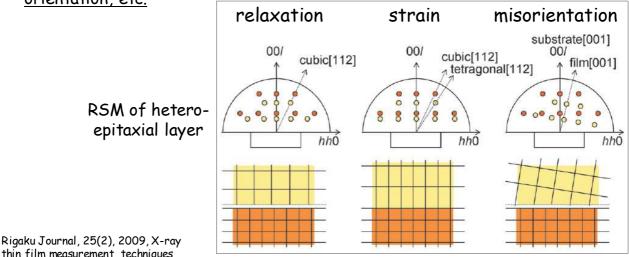


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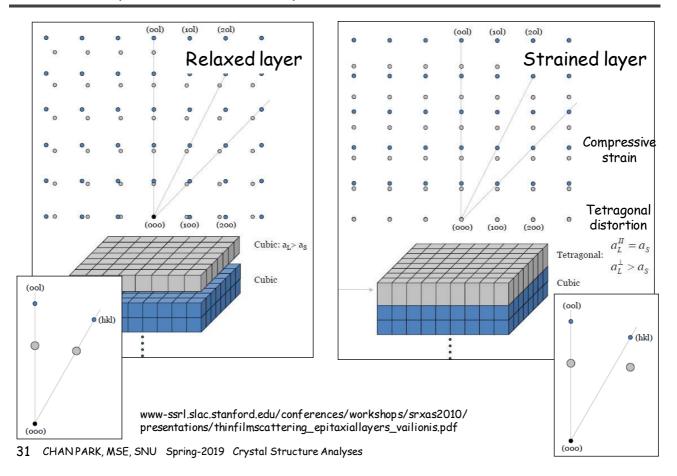
#### RSM

- RSM records diffraction intensity distributions by scanning both diffraction angle and sample rotation axes, and plots the result in the reciprocal space.
- RSM can provide <u>info on orientation relationships</u>, <u>composition</u>, <u>thickness</u>, <u>mismatch</u>, <u>relaxation</u>, <u>layer tilt</u>, <u>mosacity</u>, <u>defects profile</u>, <u>xtallinity</u>, <u>preferred</u> <u>orientation</u>, <u>etc</u>.

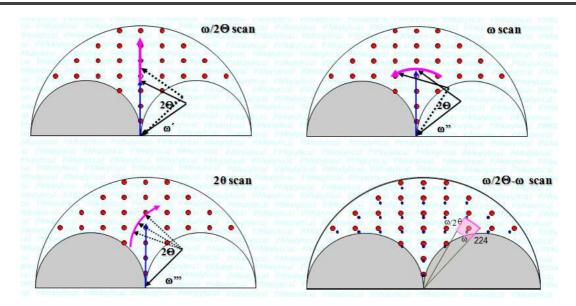


thin film measurement techniques

# Relaxed layer vs. Strained layer



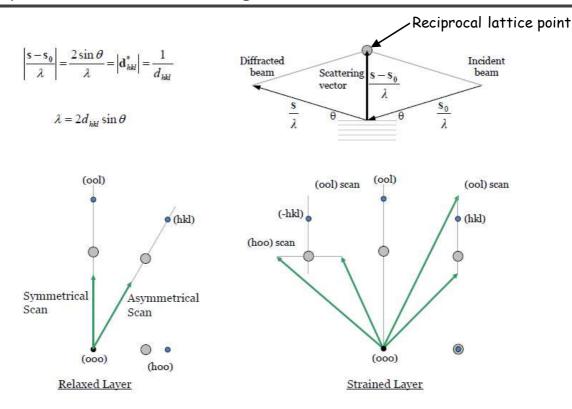
# Scans in reciprocal space



- > Rocking curve ( $\omega$  scan) arc centered on the origin
- > Detector scan ( $2\theta$  scan) arc along the Ewald sphere circumference
- > Coupled scan ( $2\theta$ - $\omega$  scan) straight line pointing away from the origin



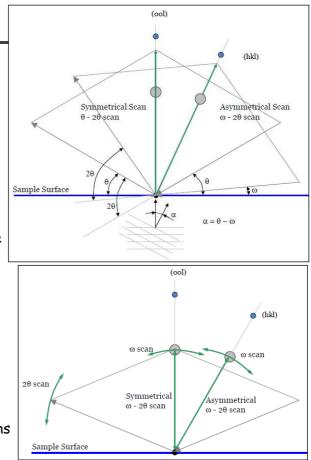
#### Reciprocal lattice - scattering vector



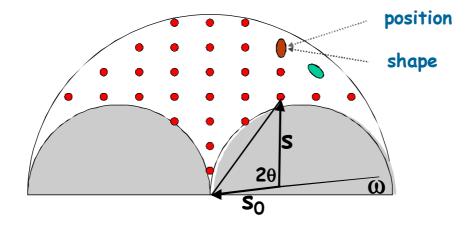
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#### Scan directions

- One family of planes is // or nearly // to the surface of the sample.
  - These are the only planes examined in a symmetric scan.
  - ✓ The sample is not tilted  $\rightarrow$  20 = 2ω
- Other planes can only be observed by tilting the sample
  - ✓ Asymmetric scans are used to collect peaks from these other planes by tilting the sample about  $\omega \rightarrow 2\theta = 2\omega + \text{tilt}$
- Several properties can only be determined by collecting both symmetric and asymmetric scans



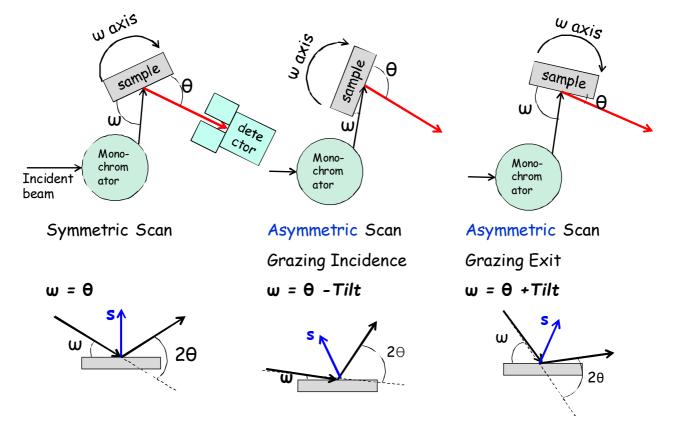
www-ssrl.slac.stanford.edu/conferences/workshops/srxas2010/presentations/thinfilmscattering\_epitaxiallayers\_vailionis.pdf 34 CHAN PARK, MSE, SNU Spring-2019 Crystal Structure Analyses Scott A. Speakman



- > Symmetrical reflection = planes parallel to surface
- > Asymmetrical reflection = planes inclined to wafer surface
  - ✓ High angle of incidence or glancing exit =  $\omega$  > 2 $\theta$ /2
  - ✓ Glancing incidence =  $\omega$  < 2 $\theta$ /2

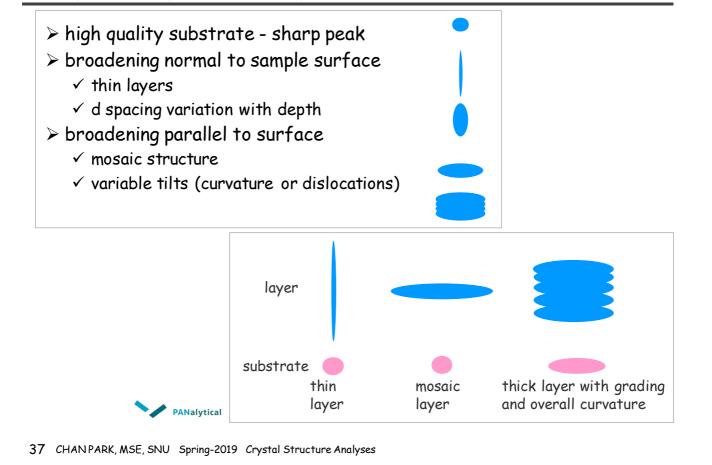
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# Symmetric vs Asymmetric

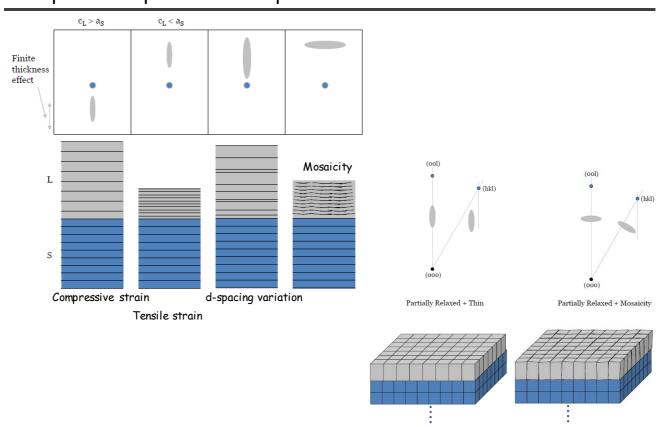


**PAN**alytical

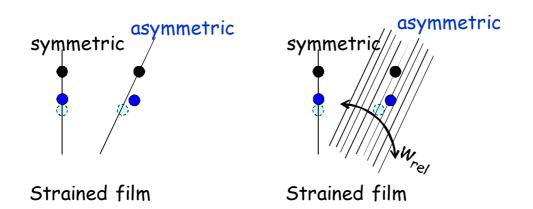
# Shape of reciprocal lattice point



# Shape of reciprocal lattice point



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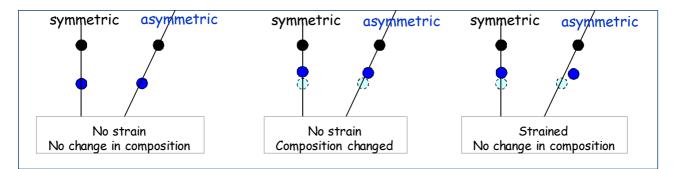
> The typical way to collect reciprocal space maps is to vary relative  $\omega$  and collect multiple  $2\theta/\omega$  coupled scans

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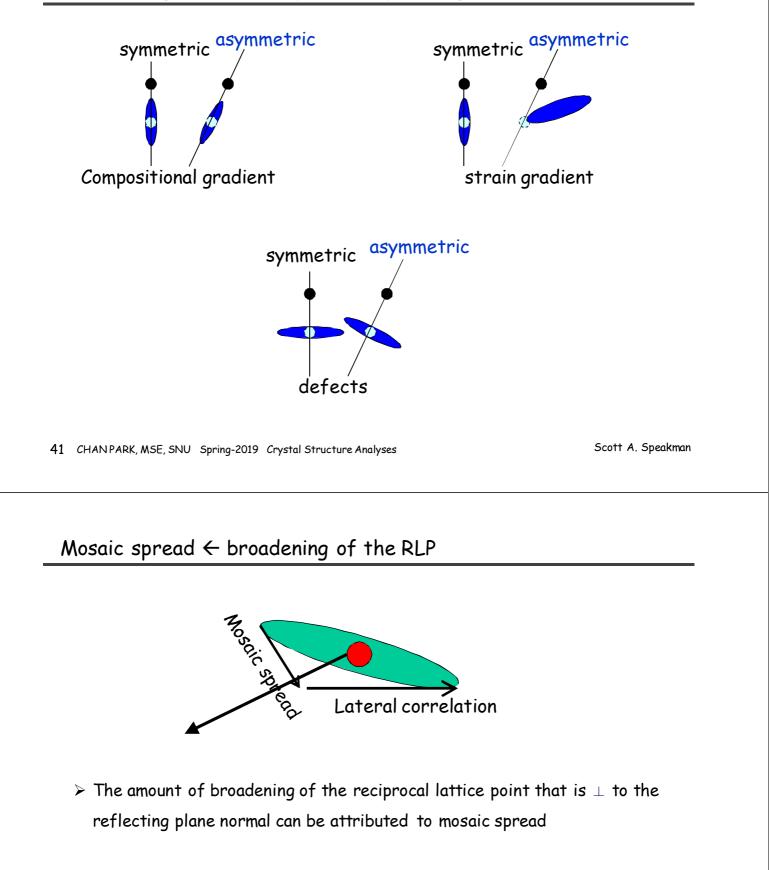
#### Change of Strain and Composition

- > In substitutional solid solutions, the composition can vary
- Changes in the composition will change the lattice parameters, which will change d<sub>hkl</sub> and t herefore the Bragg peak positions
  - ✓ Unlike relaxation, changes in composition will not change lattice tilts



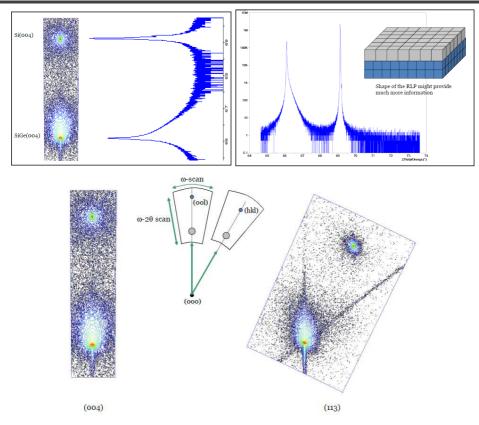
- > Symmetric scans cannot distinguish between strain & compositional changes
- > In the symmetric scan, strain and compositional changes produce similar peak shifts
- In order to quantify both strain and composition, must combine a symmetric scan with an asymmetric scan

# Defects & gradients can produce spreading of RLP



> The peak broadening // to the interface can be attributed to lateral corr elation length

# Relaxed SiGe on Si(001)

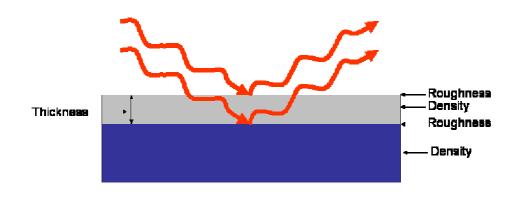


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# X-Ray Reflectivity (XRR)

- The same equipment that is optimized for HRXRD can also be used for XRR analysis of thin films.
- > X-ray waves reflecting from each different surfaces in a multilayer thin film.
  - $\checkmark$  The multiple reflected waves interfere with each other  $\rightarrow$  reflectivity curve
  - ✓ The XRR scan can be used to determine the density, thickness, and

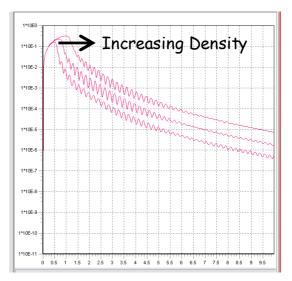
roughness of each layer in a multilayer thin film.





#### XRR > critical angle

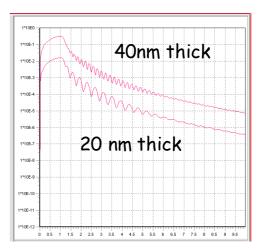
- > The critical angle is a function of the density & composition of the layer
- > Below the critical angle,  $\theta_c$ , the X-ray beam is completely reflected (total external reflection)
- The critical angle for a layer is a function of its electron density
  - This is a convolution of density and composition
  - ✓ If one is known, the other can be determined using XRR
  - ✓ For example, for a given composition, as the density of the film  $\uparrow$ , the critical angle  $\Theta_c$  often  $\uparrow$ .



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# XRR > distance between interference fringes

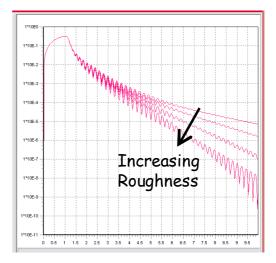
- The <u>distance between interference fringes</u> is a function of the <u>thickness</u> of the layers
- Interference fringes are created by the phase difference between X-rays reflected from different surfaces
- The distance between the fringes is inversely proportional to the thickness of the layer
  - Because of this, thicker films need better resolution (use a monochromator) and thinner films need more intensity (use only the mirror)



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# XRR > how quickly the reflected signal decays

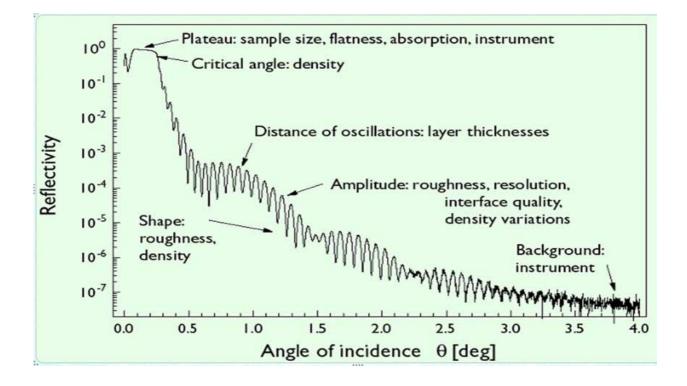
- > <u>Roughness</u> determines <u>how quickly the reflected signal decays</u>
- > Roughness causes X-rays to be scattered rather than reflected
  - $\checkmark$  This produces a decay in the reflected beam intensity
  - $\checkmark$  The loss of beam intensity  $\uparrow$  with  $\theta$
- A rougher surface produces more diffuse scatter, causing the reflected beam intensity to decay more with θ
  - The diffuse scatter can be measured to look for order in the roughness of the film.



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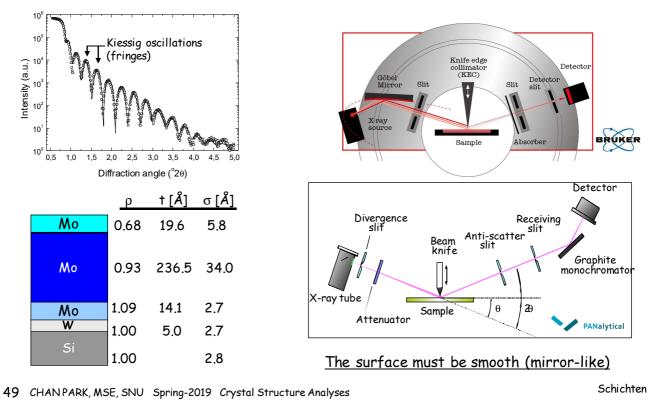
XRR



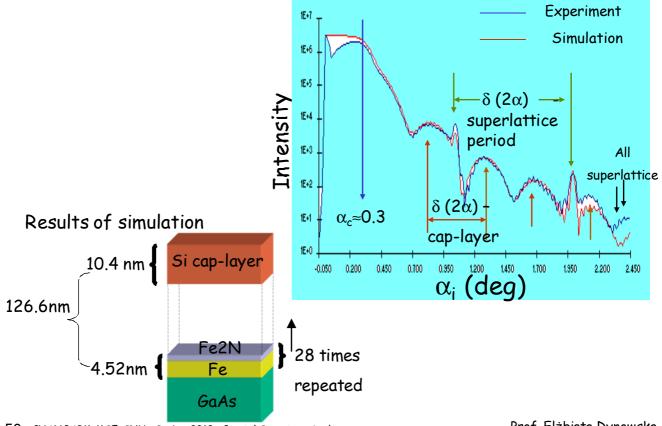


> density, thickness and interface roughness for

each layer ← multi-layer thin film



XRR > Si/{Fe/Fe2N}x28/GaAs(001) superlattice



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# XRR

# GMR Heterostructure

